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| SERIAL NUMBER 10/662,028 | FILING DATE 09/12/2003 RULE | CLASS 148 | GROUP ART UNIT 1742 | ATTORNEY DOCKET NO. YOR920030203US1 (16694) |
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APPLICANTS

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** CONTINUING DATA *****

** FOREIGN APPLICATIONS *****

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

** 12/13/2003

| Foreign Priority claimed | <input type="checkbox"/> yes <input type="checkbox"/> no | STATE OR COUNTRY | SHEETS | TOTAL | INDEPENDENT |
|---------------------------------|---|---------------------|-----------|-----------|-------------|
| 35 USC 119 (a-d) conditions met | <input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance | NY | DRAWING 7 | CLAIMS 36 | CLAIMS 2 |
| Verified and Acknowledged | Examiner's Signature _____ Initials _____ | | | | |

ADDRESS

23389
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TITLE

Formation of a silicon germanium-on-insulator structure by oxidation of a buried porous silicon layer

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| FILING FEE | FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following: | <input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) |
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